

# MCL4148

## 150mA Surface Mount Switching Diode- 100V

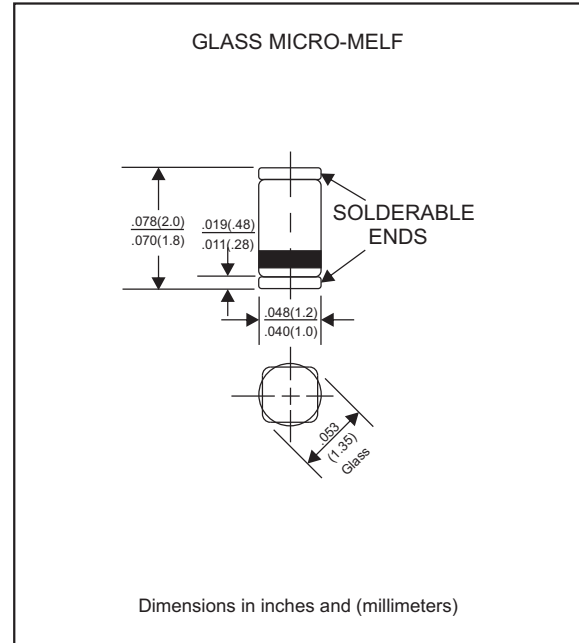
### Features

- Fast speed switching.
- For general purpose switching application.
- High conductance.
- Hermetically sealed glass
- Silicon epitaxial planar chip.
- Lead-free parts meet RoHS requirements.

### Mechanical data

- Case : GLASS MICRO-MELF
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity : Indicated by cathode band
- Mounting Position : Any
- Weight : Approximated 0.013 gram

### Package outline



### Maximum ratings and Electrical Characteristics (AT $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Repetitive peak reverse voltage		$V_{RRM}$			100	V
Reverse voltage		$V_R$			75	V
Peak forward surge current	$t_p = 1 \text{ s}$	$I_{FSM}$			500	mA
Forward current		$I_F$			300	mA
Average forward current		$I_{FAV}$			150	mA
Power dissipation		$P_V$			500	mW
Junction temperature		$T_J$	-55		+150	$^\circ\text{C}$
Storage temperature		$T_{STG}$	-65		+150	$^\circ\text{C}$
Forward voltage	$I_F = 10 \text{ mA}$	$V_F$		0.86	1.00	V
Reverse current	$V_R = 20 \text{ V}$	$I_R$			25	nA
	$V_R = 20 \text{ V}, T_J = 150^\circ\text{C}$	$I_R$			50	$\mu\text{A}$
	$V_R = 75 \text{ V}$	$I_R$			5.0	$\mu\text{A}$
Diode capacitance	$V_R = 0 \text{ V}, f = 1 \text{ MHz}$	$C_D$			4.0	pF
Reverse recovery time	$I_F = 10 \text{ mA}, V_R = 6 \text{ V}, I_{RR} = 0.1 \times I_R, R_L = 100\Omega$	$t_{rr}$			4.0	ns

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## Rating and characteristic curves (MCL4148)

Fig.1 ADMISSIBLE REPETITIVE PEAK FORWARD CURRENT VERSUS PULSE DURATION

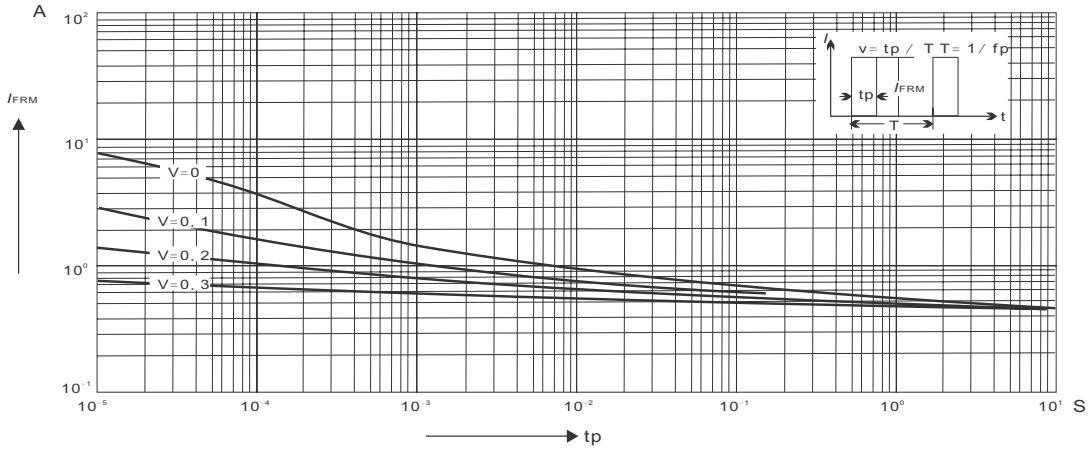


Fig.2-DYNAMIC FORWARD RESISTANCE VERSUS FORWARD CURRENT

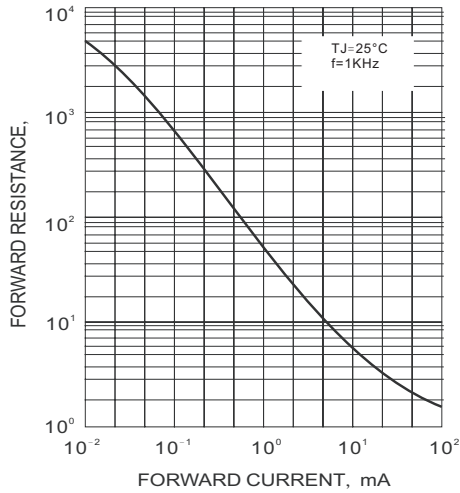


Fig.3 FORWARD CHARACTERISTICS

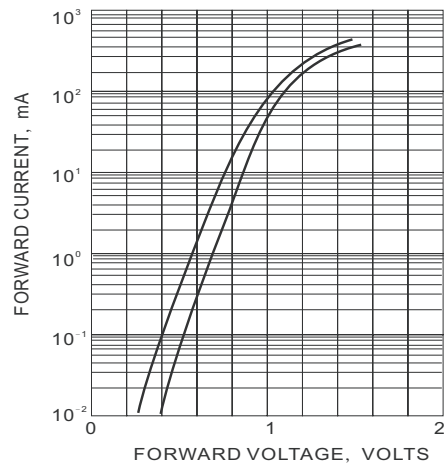


Fig.4 DERATING CURVE

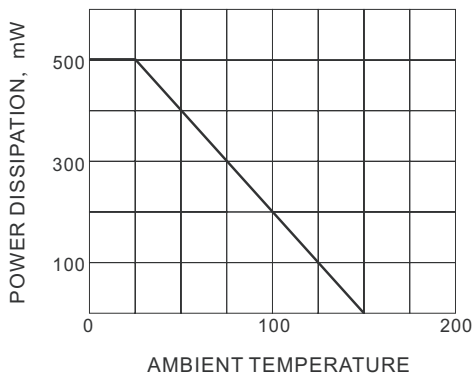
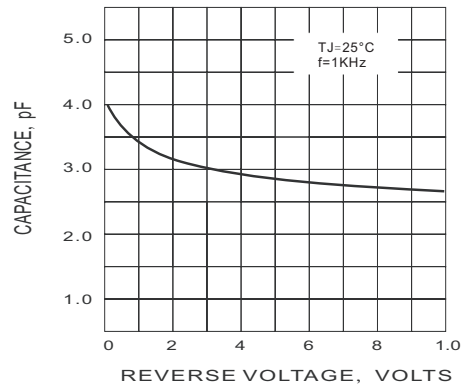




Fig.5 TYPICAL JUNCTION CAPACITANCE



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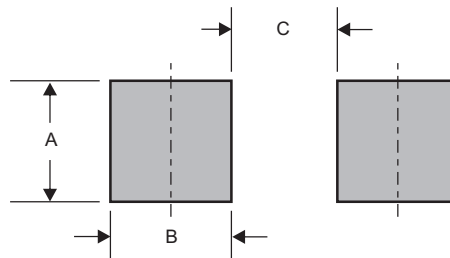
## Pinning information

Pin	Simplified outline	Symbol
Pin1 cathode Pin2 anode		

## Marking

Type number	Marking code
MCL4148	cathode band only

## Suggested solder pad layout

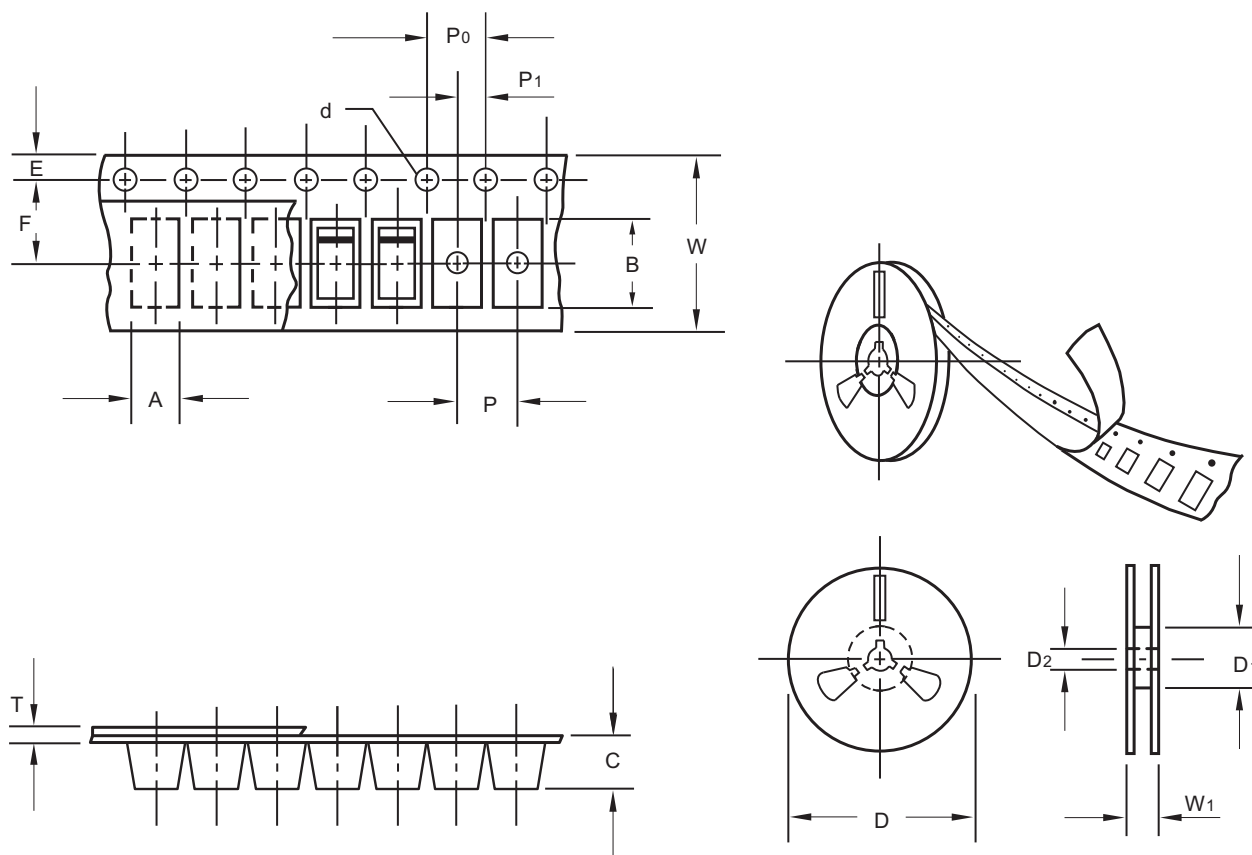


Dimensions in inches and (millimeters)

PACKAGE	A	B	C
MICRO-MELF	0.055(1.40)	0.024(0.60)	0.051(1.30)

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## Packing information



unit:mm

Item	Symbol	Tolerance	MICRO-MELF
Carrier width	A	0.1	2.00
Carrier length	B	0.1	3.70
Carrier depth	C	0.1	1.80
Sprocket hole	d	0.1	1.50
7" Reel outside diameter	D	2.0	178.00
7" Reel inner diameter	D1	min	50.00
Feed hole diameter	D2	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	3.50
Punch hole pitch	P	0.1	4.00
Sprocket hole pitch	P0	0.1	4.00
Embossment center	P1	0.1	2.00
Overall tape thickness	T	0.1	0.23
Tape width	W	0.3	8.00
Reel width	W1	0.1	11.40

Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

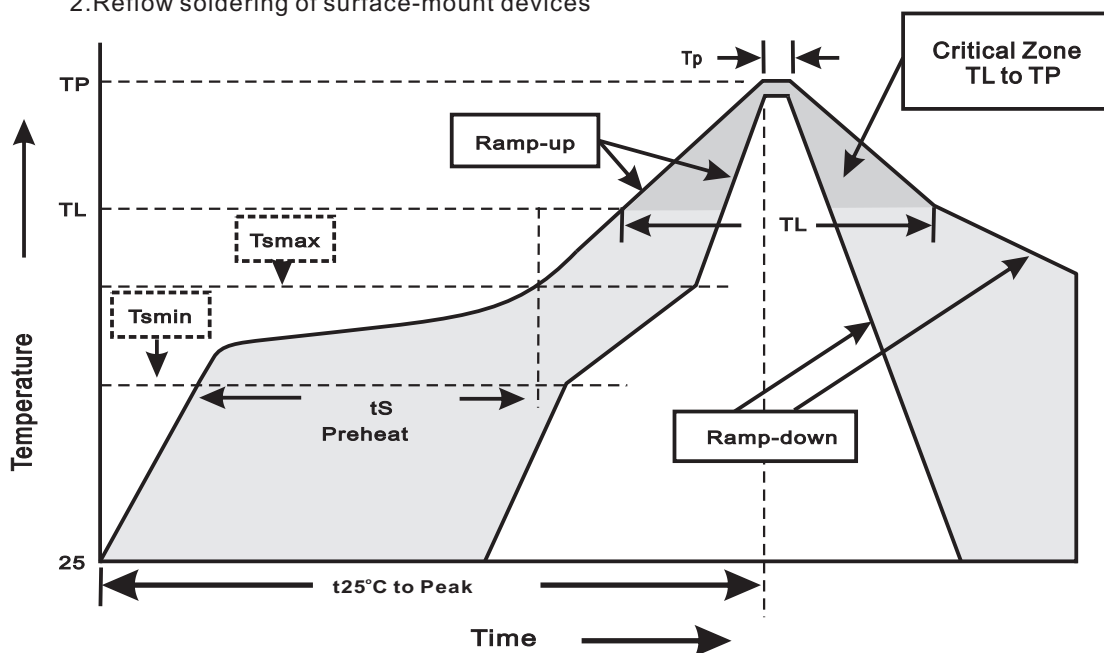
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## Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA. (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
GLASS MICRO -MELF	7"	2,500	4.0	25,000	183*183*123	178	382*262*387	200,000	9.6

## Suggested thermal profiles for soldering processes

- 1.Storage environment: Temperature=5°C~40°C Humidity=55%±25%
- 2.Reflow soldering of surface-mount devices



### 3.Reflow soldering

Profile Feature	Soldering Condition
Average ramp-up rate(T <sub>L</sub> to T <sub>P</sub> )	<3°C/sec
Preheat -Temperature Min(T <sub>Smin</sub> ) -Temperature Max(T <sub>Smax</sub> ) -Time(min to max)(t <sub>S</sub> )	150°C 200°C 60~120sec
T <sub>Smax</sub> to T <sub>L</sub> -Ramp-upRate	<3°C/sec
Time maintained above: -Temperature(T <sub>L</sub> ) -Time(t <sub>L</sub> )	217°C 60~260sec
Peak Temperature(T <sub>P</sub> )	255°C-0/+5°C
Time within 5°C of actual Peak Temperature(t <sub>P</sub> )	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes